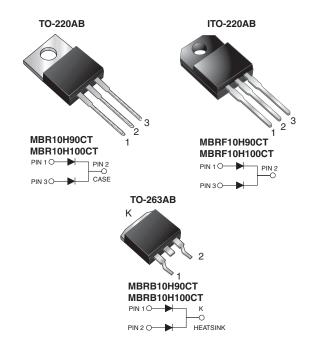


MBR(F,B)10H90CT, MBR(F,B)10H100CT

Vishay General Semiconductor

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	5 A x 2				
V _{RRM}	90 V, 100 V				
I _{FSM}	150 A				
V _F	0.61 V				
I _R	3.5 μA				
T _J max.	175 °C				

FEATURES

- · Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94-V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PARAMETER		SYMBOL	MBR10H90CT	MBR10H100CT	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	90	100		
Working peak reverse voltage		V _{RWM}	90	100	V	
Maximum DC blocking voltage		V _{DC}	90	100		
Maximum average forward rectified current at $T_C = 105 \ ^\circ C$	total device	1	10			
	per diode	I _{F(AV)}	5.0			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150		A	
Peak repetitive reverse current per diode at $t_p = 2.0 \ \mu s$, 1 kHz		I _{RRM}	0.5			
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	- 65 to 175		°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500		V	

Revision: 27-Jun-12

1

Document Number: 88668

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



COMPLIANT



Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 5 A	T _J = 25 °C	0.76	V	
		I _F = 5 A	T _J = 125 °C	0.61		
		I _F = 10 A	T _J = 25 °C	0.85		
		I _F = 10 A	T _J = 125 °C	0.71		
Maximum reverse current per diode	I _R ⁽¹⁾	Rated V _R	T _J = 25 °C	3.5	μA	
			T _J = 100 °C	4.5	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_c = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	2.2	5.2	2.2	°C/W

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR10H100CT-E3/45	1.85	45	50/tube	Tube	
ITO-220AB	MBRF10H100CT-E3/45	1.79	45	50/tube	Tube	
TO-263AB	MBRB10H100CT-E3/45	1.35	45	50/tube	Tube	
TO-263AB	MBRB10H100CT-E3/81	1.35	81	800/reel	Tape and reel	
TO-220AB	MBR10H100CTHE3/45 ⁽¹⁾	1.85	45	50/tube	Tube	
ITO-220AB	MBRF10H100CTHE3/45 (1)	1.79	45	50/tube	Tube	
TO-263AB	MBRB10H100CTHE3/45 (1)	1.35	45	50/tube	Tube	
TO-263AB	MBRB10H100CTHE3/81 (1)	1.35	81	800/reel	Tape and reel	

Note

(1) AEC-Q101 qualified

2



MBR(F,B)10H90CT, MBR(F,B)10H100CT

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

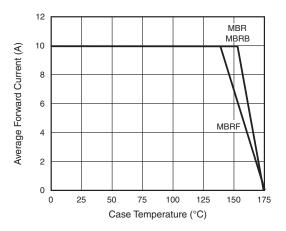


Fig. 1 - Forward Current Derating Curve Per Diode

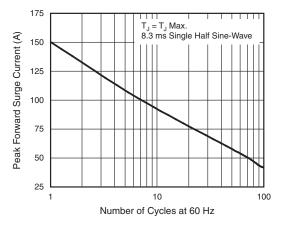


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

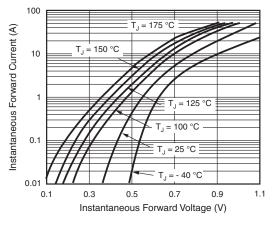


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

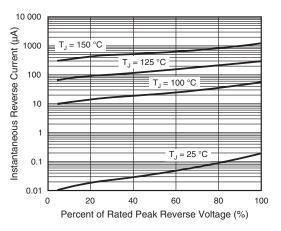


Fig. 4 - Typical Reverse Characteristics Per Diode

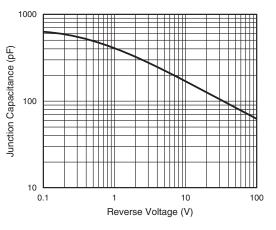
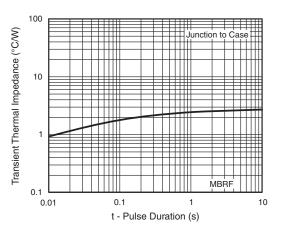
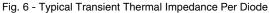


Fig. 5 - Typical Junction Capacitance Per Diode





Revision: 27-Jun-12

3

Document Number: 88668

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



MBR(F,B)10H90CT, MBR(F,B)10H100CT

Vishay General Semiconductor

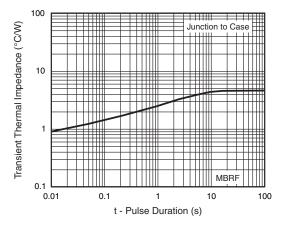


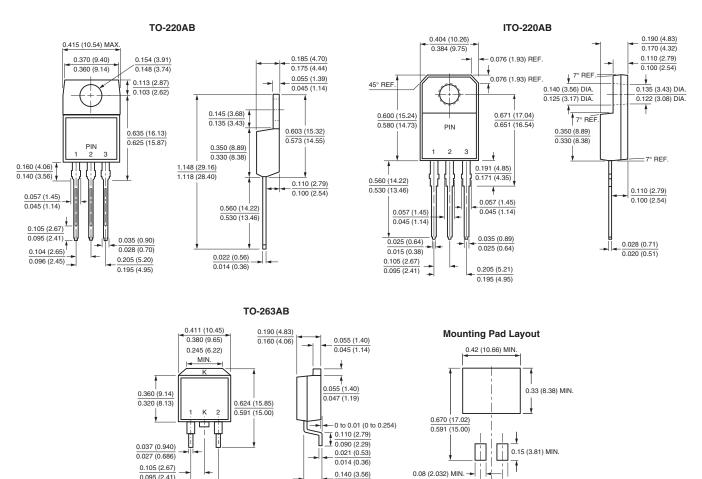
Fig. 7 - Typical Transient Thermal Impedance Per Diode

0.095 (2.41)

0.205 (5.20)

0.195 (4.95)

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Revision: 27-Jun-12 Document Number: 88668 4 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

0.110 (2.79)

0.105 (2.67) 0.095 (2.41)



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

 MBR10H100/45
 MBR10H100CT/45
 MBR10H100CT-E3/45
 MBRB10H100CT/31
 MBRB10H100CT/81

 MBRB10H100CT-E3/31
 MBRB10H100CT-E3/81
 MBRB10H90CT/81
 MBRB10H90CT-E3/31
 MBRF10H100CT-E3/45

 MBRF10H90CT-E3/45
 MBR10H100CTHE3/45
 MBRB10H100CTHE3/45
 MBRB10H100CTHE3/45
 MBRB10H100CTHE3/45

 MBRF10H100CTHE3/45
 MBRB10H100CTHE3/45
 MBRB10H100CTHE3/45
 MBRB10H100CTHE3/45